A wide-bandgap copolymer donor with a

5-methyl-4H-dithieno[3,2-e:2',3'-g]isoindole-4,6(5H)-dione unit

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1. General characterization

¹H and ¹³C NMR spectra were measured on a Bruker Avance-400 spectrometer. Absorption spectra were recorded on a Shimadzu UV-1800 spectrophotometer. Cyclic voltammetry was done by using a Shanghai Chenhua CHI620D voltammetric analyzer under argon in an anhydrous acetonitrile solution of tetra-n-butylammonium hexafluorophosphate (0.1 M). A glassy-carbon electrode was used as the working electrode, a platinum-wire was used as the counter electrode, and a Ag/Ag⁺ electrode was used as the reference electrode. Polymers were coated onto glassy-carbon electrode and all potentials were corrected against Fc/Fc⁺. AFM was performed on a Multimode microscope (Veeco) by using tapping mode.



Fig. S1 DFT-predicted HOMO and LUMO for (a) D18 and (b) P1.

3. Synthesis

All reagents were purchased from J&K Co., Aladdin Co., Innochem Co., Derthon Co., SunaTech Co. and other commercial suppliers. N3 was purchased from eFlexPV Co. All reactions dealing with air- or moisture-sensitive compounds were carried out by using standard Schlenk techniques.

Compound 1. To a solution of 3,4-dibromo-1-methyl-1H-pyrrole-2,5-dione (2.31 g, 8.2 mmol) and tributyl(thiophen-3-yl)stannane (8.99 g, 22.9 mmol) in DMF (45 mL) was added Pd(PPh₃)₄ (497 mg, 0.41 mmol) under N₂. The mixture was heated to reflux and stirred overnight. After removal of the solvent, the crude product was purified via column chromatography (silica gel) by using CH₂Cl₂ as eluent to give **compound 1** as a yellow solid (1.97 g, 83%). ¹H NMR (CDCl₃, 400 MHz, δ /ppm): 7.98 (dd, $J_1 = 3.2$ Hz, $J_2 = 1.2$ Hz, 2H), 7.34 (dd, $J_1 = 5.2$ Hz, $J_2 = 2.8$ Hz, 2H), 7.25 (dd, $J_1 = 4.8$ Hz, $J_2 = 1.2$ Hz, 2H), 3.12 (s, 3H). ¹³C NMR (CDCl₃, 100 MHz, δ /ppm): 171.02, 129.37, 129.30, 129.27, 127.52, 125.76, 24.17. EI MS (m/z): C₁₃H₉NO₂S₂ (M⁺) calc. 275.34, found 275.

MDTID. To a solution of compound 1 (1.00 g, 3.6 mmol) in dry CH₂Cl₂ (200 mL) was added FeCl₃ (4.71 g, 29.1 mmol) under N₂. The mixture was stirred at room temperature for 5 h. Then, the resulting mixture was filtered and the filtrate was collected. After removal of the solvent, the residue was washed with n-hexane to give **MDTID** as a yellow solid (424 mg, 43%). ¹H NMR (CDCl₃, 400 MHz, δ /ppm): 8.11 (d, *J* = 5.6 Hz, 2H), 7.70 (d, *J* = 5.2 Hz, 2H), 3.24 (s, 3H). ¹³C NMR (CDCl₃, 100 MHz, δ /ppm): 169.06, 139.51, 130.75, 128.83, 123.71, 122.35, 23.79. EI MS (m/z): C₁₃H₇NO₂S₂ (M⁺) calc. 273.32, found 273.

MDTID-Br. To a solution of MDTID (230 mg, 0.84 mmol) in CHCl₃ (23 mL) were added NBS (320 mg, 1.80 mmol) and H₂SO₄ (0.7 mL). The mixture was stirred at room temperature for 30 min. Another potion of NBS (76 mg, 0.427 mmol) and H₂SO₄ (0.2 ml) were added. After 1 h, methanol/water (20/1) was added to quench the reaction. The resulting mixture was filtered to give **MDTID-Br** as a yellow solid (325 mg, 90%). Due to the extremely low solubility of MDTID-Br, NMR data were not acquired. MALDI-TOF MS (m/z): C₁₃H₅Br₂NO₂S₂ (M⁺) calc. 431.12, found 432.21.

Compound 2. To a solution of MDTID-Br (300 mg, 0.70 mmol) and tributyl(4-(2-butyloctyl)thiophen-2-yl)stannane (944 mg, 1.74 mmol) in toluene (10 mL) and DMF (2 mL) was added Pd(PPh₃)₄ (82 mg, 0.07 mmol) under N₂. The mixture was heated to reflux and stirred overnight. After cooling to room temperature, the mixture was dried over anhydrous Na₂SO₄. After removal of the solvent, the crude product was purified via column chromatography (silica gel) by using CH₂Cl₂:petroleum ether (1:2) as eluent to give **compound 2** as a yellow oil (220 mg, 41%). ¹H NMR (CDCl₃, 400 MHz, δ /ppm): 7.83 (s, 2H), 7.12 (s, 2H), 6.92 (s, 2H), 3.10 (s, 3H), 2.55 (d, *J* = 6.8 Hz, 4H), 1.66-1.64 (m, 2H), 1.34-1.28 (m, 32H), 0.94-0.88 (m, 12H). ¹³C NMR (CDCl₃, 100 MHz, δ /ppm):168.69, 143.25, 140.95, 137.39, 135.50, 131.76, 127.95, 122.93, 122.54, 116.69, 38.83, 34.93, 33.30, 32.97, 31.92, 29.71, 28.84, 26.59, 23.61, 23.07, 22.70, 14.17, 14.14. MALDI-TOF MS (m/z): C₄₅H₅₉NO₂S₂ (M⁺) calc. 774.21, found 774.84.

M1. To a solution of compound 2 (220 mg, 0.28 mmol) in CHCl₃ (25 mL) was added NBS (106 mg, 0.60 mmol). The mixture was stirred for 2 h. Then methanol was added and the resulting mixture was filtered. The precipitate was collected and was purified via column chromatography (silica gel) by using CH₂Cl₂:petroleum ether (1:2) as eluent to give **M1** as a yellow solid (215 mg, 81%). ¹H NMR (CDCl₃, 400 MHz, δ/ppm): 7.96 (s, 2H), 7.06 (s, 2H), 3.23 (s, 3H), 2.53 (d, J = 7.2 Hz, 4H), 1.72-1.69 (m, 2H), 1.35-1.26 (m, 32H), 0.93-0.88 (m, 12H). ¹³C NMR (CDCl₃, 100 MHz, δ/ppm): 168.50, 142.72, 139.91, 137.21, 135.17, 131.69, 127.37, 123.11, 116.94, 111.62, 38.53, 34.22, 33.32, 33.01, 31.91, 29.71, 28.75, 26.50, 23.75, 23.07, 22.71, 14.16, 14.15. MALDI-TOF MS (m/z): C₄₅H₅₇Br₂NO₂S₂ (M⁺) calc. 932.00, found 931.71.

P1. To a mixture of M1 (80 mg, 0.086 mmol), FBDT-Sn (80.7 mg, 0.086 mmol), $Pd_2(dba)_3$ (2.4 mg, 0.0026 mmol) and $P(o-tol)_3$ (7.8 mg, 0.026 mmol) in a Schlenk flask was added toluene (0.8 mL) under argon. The mixture was heated to reflux for 16 h. Then, 8 mL chlorobenzene was added and the mixture was stirred at 110 °C for 10 min. The solution was added into 100 mL methanol dropwise. The precipitate was collected and further purified via Soxhlet extraction by using CH₂Cl₂, CH₂Cl₂:CHCl₃ (1:1), CHCl₃ in sequence. The chloroform fraction was concentrated and added into methanol dropwise. The precipitate was collected and dried under vacuum overnight to give **P1** as a brown solid (89 mg, 75%). The M_n for P1 is 69.7 kDa, with a PDI of

1.73. ¹H NMR (CDCl₃, 400 MHz, δ /ppm): 7.95-6.84 (br, aromatic protons), 3.39-2.87 (br, aliphatic protons), 1.54-0.88 (br, aliphatic protons).

4. NMR



Fig. S3 ¹³C NMR spectrum of compound 1.











Fig. S9 ¹³C NMR spectrum of M1.



Fig. S10 ¹H NMR spectrum of P1.

5. CV



Fig. S11 Cyclic voltammogram for P1.

6. Energy levels



Fig. S12 HOMO and LUMO levels for P1, N3^[1] and IT-4F^[2].

7. Device fabrication and measurements

Conventional solar cells

A 30 nm thick PEDOT:PSS layer was made by spin-coating an aqueous dispersion onto ITO glass (4000 rpm for 30 s). PEDOT:PSS substrates were dried at 150 °C for 10 min. A P1:N3 blend in chloroform (CF) (or a P1:IT-4F blend in chlorobenzene (CB)) was spin-coated onto PEDOT:PSS. PDIN (2 mg/mL) in MeOH:AcOH (1000:3) was spin-coated onto active layer (5000 rpm for 30 s). Ag (~80 nm) was evaporated onto PDIN through a shadow mask (pressure ca. 10^{-4} Pa). The effective area for the devices is 4 mm². The thicknesses of the active layers were measured by using a KLA Tencor D-120 profilometer. *J-V* curves were measured by using a computerized Keithley 2400 SourceMeter and a Xenon-lamp-based solar simulator (Enli Tech, AM 1.5G, 100 mW/cm²). The illumination intensity of solar simulator was determined by using a monocrystalline silicon solar cell (Enli SRC2020, 2cm×2cm) calibrated by NIM. The external quantum efficiency (EQE) spectra were measured by using a QE-R3011 measurement system (Enli Tech).

Hole-only devices

The structure for hole-only devices is ITO/PEDOT:PSS/active layer/MoO₃/Al. A 30 nm thick PEDOT:PSS layer was made by spin-coating an aqueous dispersion onto ITO glass (4000 rpm for 30 s). PEDOT:PSS substrates were dried at 150 °C for 10 min. A pure P1 in CF (or a P1:N3 blend in CF; or a P1:IT-4F blend in CB) was spin-coated onto PEDOT:PSS. Finally, MoO₃ (~6 nm) and Al (~100 nm) was successively evaporated onto the active layer through a shadow mask (pressure ca. 10^{-4} Pa). J-V curves were measured by using a computerized Keithley 2400

SourceMeter in the dark.

Electron-only devices

The structure for electron-only devices is Al/active layer/Ca/Al. Al (~80 nm) was evaporated onto a glass substrate. A P1:N3 blend in CF (or a P1:IT-4F blend in CB) was spin-coated onto Al. Ca (~5 nm) and Al (~100 nm) were successively evaporated onto the active layer through a shadow mask (pressure ca. 10^{-4} Pa). *J-V* curves were measured by using a computerized Keithley 2400 SourceMeter in the dark.

8. Optimization of device performance

D/A [w/w]	$V_{ m oc}$ [V]	J _{sc} [mA/cm ²]	FF [%]	PCE [%]
1:0.8	0.92	22.26	54.8	11.23 (11.11) ^b
1:1.2	0.90	24.52	65.8	14.52 (14.25)
1:1.6	0.90	24.47	62.7	13.81 (13.68)
1:2	0.90	24.19	63.2	13.77 (13.51)

Table S1 Optimization of D/A ratio for P1:N3 conventional solar cells.^a

^{*a*}Blend solution: 14.5 mg/mL in CF; spin-coating: 4000 rpm for 30 s. ^{*b*}Data in parentheses are averages for 8 cells.

Table S2 Optimization of active layer thickness for P1:N3 conventional solar cells.^a

Thickness [nm]	$V_{ m oc}$ [V]	J _{sc} [mA/cm ²]	FF [%]	PCE [%]
145	0.90	22.98	56.4	11.66 (11.36) ^b
115	0.91	24.09	61.2	13.42 (13.28)
100	0.90	24.52	65.8	14.52 (14.25)
85	0.91	23.60	64.4	13.83 (13.62)
70	0.91	23.20	64.2	13.55 (13.47)

^{*a*}D/A ratio: 1:1.2 (w/w); blend solution: 14.5 mg/mL in CF. ^{*b*}Data in parentheses are averages for 8 cells.

DIO [vol%]	V _{oc} [V]	$J_{\rm sc}$ [mA/cm ²]	FF [%]	PCE [%]
0	0.90	24.52	65.8	14.52 (14.25) ^b
0.1	0.91	24.86	62.6	14.16 (13.82)
0.3	0.90	24.81	56.6	12.64 (12.50)
0.5	0.90	24.18	54.5	11.86 (11.62)

Table S3 Optimization of DIO content for P1:N3 conventional solar cells.^a

 $^a\mathrm{D/A}$ ratio: 1:1.2 (w/w); blend solution: 14.5 mg/mL in CF; spin-coating: 4000 rpm for 30 s.

^{*b*}Data in parentheses stand are averages for 8 cells.

Table S4 Optimization of D/A ratio for P1:IT-4F conventional solar cells.^a

D/A [w/w]	$V_{ m oc}$ [V]	$J_{\rm sc}$ [mA/cm ²]	FF [%]	PCE [%]
1:0.8	0.96	17.60	54.7	$9.24 (9.03)^b$
1:1.2	0.97	18.50	56.9	10.21 (10.04)
1:1.6	0.97	16.77	59.9	9.74 (9.48)
1:2	0.96	15.16	59.7	8.67 (8.46)

^{*a*}Blend solution: 15.6 mg/mL in CB; spin-coating: 4000 rpm for 30 s.

^bData in parentheses are averages for 8 cells.

Thickness [nm]	$V_{ m oc}$ [V]	$J_{\rm sc}$ [mA/cm ²]	FF [%]	PCE [%]
160	0.95	17.29	45.8	7.52 (7.35) ^b
135	0.96	18.38	52.1	9.19 (8.87)
115	0.97	18.50	56.9	10.21 (10.04)
95	0.96	18.14	56.7	9.87 (9.65)
80	0.96	17.29	58.5	9.71 (9.45)

Table S5 Optimization of active layer thickness for P1:IT-4F conventional solar cells.^a

^{*a*}D/A ratio: 1:1.2 (w/w); blend solution: 15.6 mg/mL in CB. ^{*b*}Data in parentheses are averages for 8 cells.

Table S6 Optimization of DIO content for P1:IT-4F conventional solar cells.^a

DIO [vol%]	$V_{ m oc}$ [V]	$J_{\rm sc}$ [mA/cm ²]	FF [%]	PCE [%]
0	0.97	18.50	56.9	10.21 (10.04) ^b
0.3	0.95	19.63	66.3	12.36 (12.17)
0.5	0.95	20.31	64.6	12.46 (12.29)
0.7	0.92	13.12	39.2	4.73 (4.52)

 $^a\mathrm{D/A}$ ratio: 1:1.2 (w/w); blend solution: 15.6 mg/mL in CB; spin-coating: 4000 rpm for 30 s.

^bData in parentheses stand are averages for 8 cells.

9. SCLC

Charge carrier mobility was measured by SCLC method. The mobility was determined by fitting the dark current to the model of a single carrier SCLC, which is described by:

$$J = \frac{9}{8}\varepsilon_0\varepsilon_r \mu \frac{V^2}{d^3}$$

where J is the current density, μ is the zero-field mobility of holes (μ_h) or electrons (μ_e), ε_0 is the permittivity of the vacuum, ε_r is the relative permittivity of the material, d is the thickness of the blend film, and V is the effective voltage ($V = V_{appl} - V_{bi}$, where V_{appl} is the applied voltage, and V_{bi} is the built-in potential determined by electrode work function difference). Here, $V_{bi} = 0.1$ V for hole-only devices, $V_{bi} = 0$ V for electron-only devices.^[3] The mobility was calculated from the slope of $J^{1/2}$ -V plot.



Fig. S13 *J-V* curve (a) and corresponding $J^{1/2}$ -*V* plot (b) for the hole-only devices (in dark). The thickness for P1 pure film is 109 nm.



Fig. S14 *J-V* curves (a) and corresponding $J^{1/2}$ -*V* plots (b) for the hole-only devices (in dark). The thicknesses for P1:N3 and P1:IT-4F films are 105 nm and 103 nm, respectively.



Fig. S15 J-V curves (a) and corresponding $J^{1/2}$ -V plots (b) for the electron-only devices (in dark). The thicknesses for P1:N3 and P1:IT-4F films are 104 and 105 nm, respectively.

Table S7 Hole and electron mobilities.					
Films	μ <i>t</i> h	$\mu_{ m e}$	11-11-		
	$[cm^2/Vs]$ $[cm^2/Vs]$		μιν με		
P1	7.10×10 ⁻⁴	-	-		
P1:N3 (1:1.2)	3.90×10 ⁻⁴	2.63×10 ⁻⁴	1.48		
P1:IT-4F (1:1.2)	2.45×10 ⁻⁴	1.19×10 ⁻⁴	2.06		

Table S7	Hole	and	electron	mobilitie
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10. Bimolecular recombination



Fig. S16 *J*_{sc}-*P*_{light} plots.



Fig. S17 AFM height (left) and phase (right) images for the blend films. (a) and (b), P1:N3 and film ($R_{\rm rms} = 0.80$ nm); (c) and (d), P1:IT-4F film ($R_{\rm rms} = 1.76$ nm). $R_{\rm rms}$: root-mean-square roughness.

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